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**ON Semiconductor®** 

# FDD6637-F085

# P-Channel PowerTrench<sup>®</sup> MOSFET -35V, -21A, 18m $\Omega$

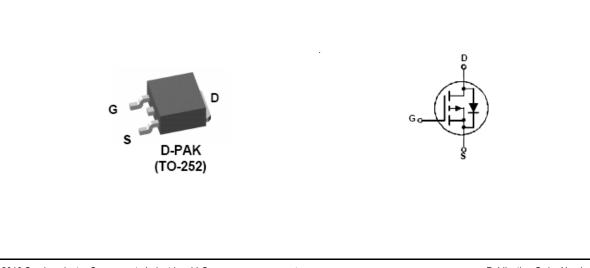
## Features

- Typ  $r_{DS(on)}$  = 9.7m $\Omega$  at V<sub>GS</sub> = -10V, I<sub>D</sub> =- 14A
- Typ  $r_{DS(on)}$  = 14.4m $\Omega$  at V<sub>GS</sub> = -4.5V, I<sub>D</sub> =- 11A
- Typ  $Q_{g(10)}$  = 45nC at  $V_{GS}$  = -10V
- High performance trench technology for extremely low r<sub>DS(on)</sub>.
- Qualified to AEC Q101
- RoHS Compliant

## Applications

- Inverter
- Power Supplies





### **MOSFET Maximum Ratings** $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Ratings	Units
V <sub>DSS</sub>	Drain to Source Voltage	-35	V
V <sub>DS(Avalanche)</sub>	Drain to Source Avalanche Voltage (maximum)	-45	V
V <sub>GS</sub>	Gate to Source Voltage	±25	V
l	Drain Current Continuous (T <sub>C</sub> < 155°C, V <sub>GS</sub> = 10V)	-21	^
D	Pulsed	See Figure 4	- A
E <sub>AS</sub>	Single Pulse Avalanche Energy (Note 1)	61	mJ
D	Power Dissipation	68	W
P <sub>D</sub>	Dreate above 25°C	0.46	W/ºC
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature	-55 to + 175	°C

#### **Thermal Characteristics**

$R_{ ext{ heta}JC}$	Maximum Thermal Resistance Junction to Case	2.2	°C/W
$R_{ hetaJA}$	Maximum Thermal Resistance Junction to Ambient TO-252, 1in <sup>2</sup> copper pad area	40	°C/W

# Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD6637	FDD6637-F085	TO-252	13"	12mm	2500 units

# **Electrical Characteristics** $T_{C}$ = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units

#### **Off Characteristics**

B <sub>VDSS</sub>	Drain to Source Breakdown Voltage	$I_{D} = 250 \mu A, V_{GS} = 0 V$	-35	-	-	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS}$ = -28V, $V_{GS}$ = 0V	-	-	-1	μA
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS} = \pm 25V$	-	-	±100	nA

#### **On Characteristics**

V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = -250 \mu A$	-1	-1.6	-3	V
		I <sub>D</sub> = -14A, V <sub>GS</sub> = -10V	-	9.7	11.6	
r <sub>DS(on)</sub>	Drain to Source On Resistance	I <sub>D</sub> = -11A, V <sub>GS</sub> = -4.5V	-	14.4	18	mΩ
		$I_D$ = -14A, $V_{GS}$ = -10V, $T_C$ = 150°C	-	15.3	18	
9 <sub>FS</sub>	Forward Transconductance	$V_{DS} = -5V, I_D = -14A$	-	35	-	S

#### **Dynamic Characteristics**

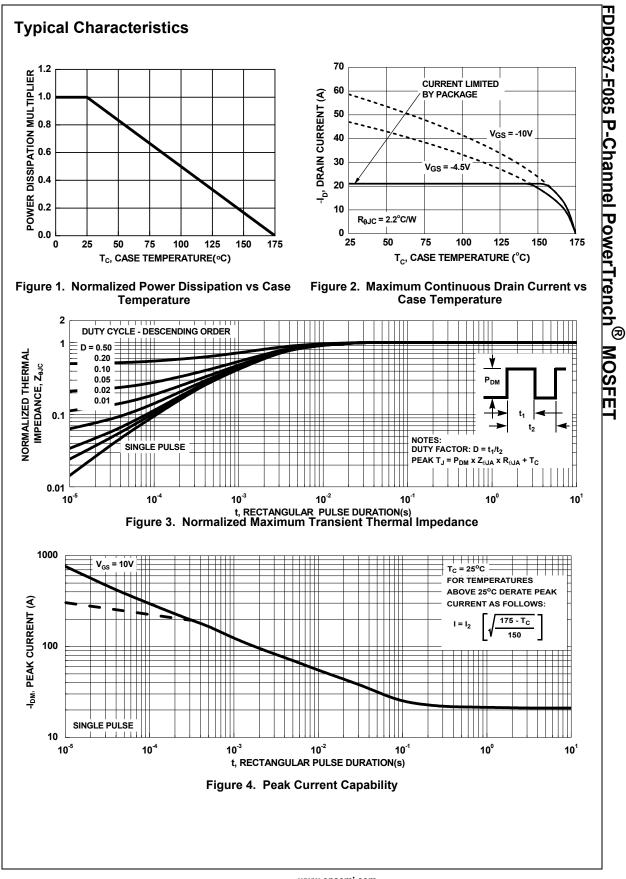
C <sub>iss</sub>	Input Capacitance		0)/	-	2370	-	pF
C <sub>oss</sub>	Output Capacitance	V <sub>DS</sub> = -20V, V <sub>GS</sub> = f = 1MHz	υν,	-	470	-	pF
C <sub>rss</sub>	Reverse Transfer Capacitance			-	250	-	pF
R <sub>G</sub>	Gate Resistance	f = 1MHz		-	3.6	-	Ω
Q <sub>g(TOT)</sub>	Total Gate Charge at -10V	V <sub>GS</sub> = 0 to -10V		-	45	63	nC
Q <sub>g(5)</sub>	Total Gate Charge at -5V	$V_{GS}$ = 0 to -5V	V <sub>DD</sub> = -20V	-	25	35	nC
Q <sub>gs</sub>	Gate to Source Gate Charge		I <sub>D</sub> = -14A	-	7	-	nC
Q <sub>gd</sub>	Gate to Drain "Miller" Charge			-	10	-	nC

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Switch	ning Characteristics					
t <sub>d(on)</sub>	Turn-On Delay Time		-	18	32	ns
t <sub>r</sub>	Rise Time	$V_{DD}$ = -20V, I <sub>D</sub> = -1A, $V_{GS}$ = -10V, $R_{GEN}$ = 6Ω	-	10	20	ns
t <sub>d(off)</sub>	Turn-Off Delay Time		-	62	100	ns
t <sub>f</sub>	Fall Time	I GEN - 052	-	36	58	ns

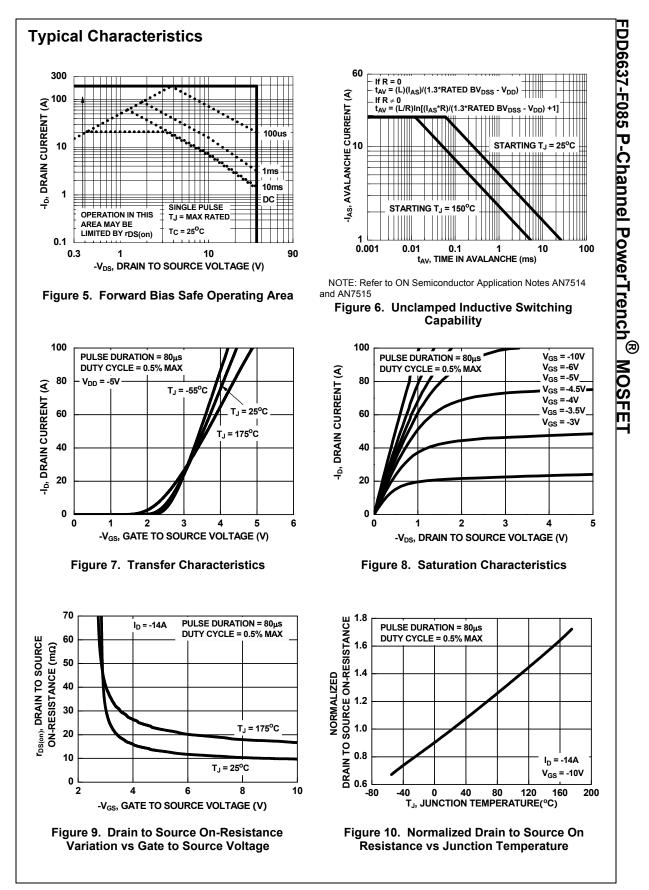
Notes:

1: Starting  $T_J = 25^{\circ}$ C, L = 1mH,  $I_{AS} = -11A$ ,  $V_{GS} = 10V$ ,  $V_{DD} = -35V$  during the inductor charging time and 0V during the time in avalanche

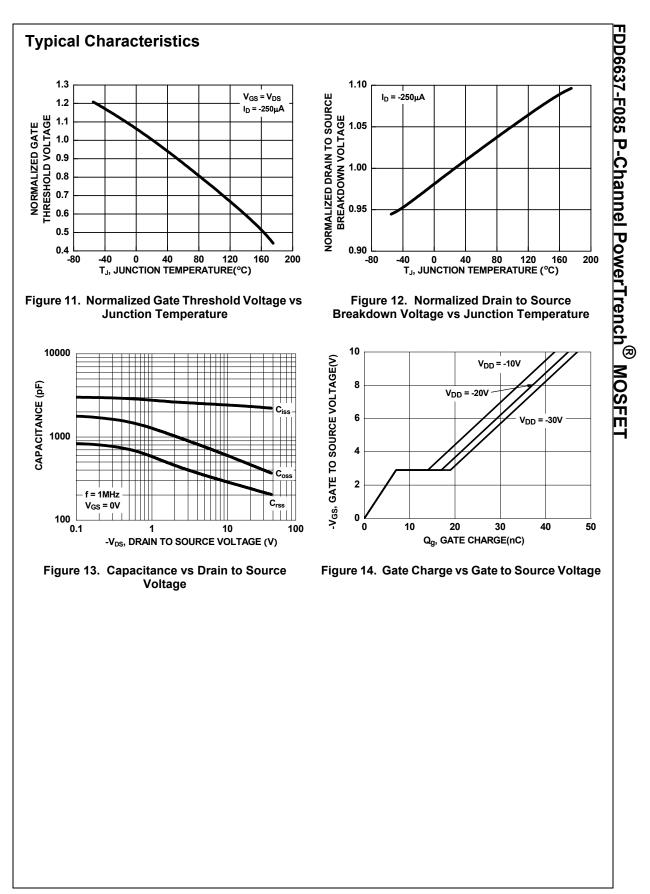
This product has been designed to meet the extreme test conditions and environment demanded by the automotive industry. For a copy of the requirements, see AEC Q101 at: http://www.aecouncil.com/



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